

Product Summary

V_{RRM} (V)	I_O (A)	V_F (Max) (V) @ +25°C	I_R (Typ) (μ A) @ +25°C
650	4	1.5	0.11

Description and Applications

Packaged in the robust industry-standard DFN8080 package, the DSC04A065LP provides excellent reverse leakage stability at high temperatures. It is ideal for use as a rectifier, freewheel diode, or blocking diode in:

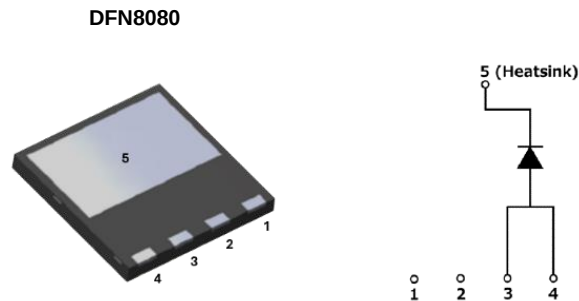
- Power factor correction
- Industrial motor drivers
- Power inverters
- SMPS
- UPS

Features and Benefits

- Low Conduction and Switching Loss
- High-Temperature Application
- Positive Temperature Coefficient on V_F
- Fast Reverse Recovery
- High Surge Current Capability
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.
<https://www.diodes.com/quality/product-definitions/>

Mechanical Data

- Package: DFN8080
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 
- Weight: 0.214 grams (Approximate)

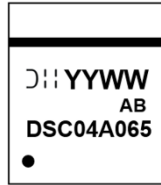


Ordering Information (Note 4)

Orderable Part Number	Package	Packing	
		Qty.	Carrier
DSC04A065LP-13	DFN8080	2,500	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



DSC04A065LP = Manufacturer's Marking
 DSC04A065 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 24 = 2024)
 WW = Week (01 to 53)
 AB = Fab and Assembly Code

Maximum Ratings (@T_C = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	650	V
DC Blocking Voltage	V _{DC}	650	V
Average Rectified Output Current	I _O	4	A
Non-Repetitive Peak Forward Surge Current 10ms Half Sine Waveform	I _{FSM}	29	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Notes 5, 6, 7)	R _{θJC}	1.88	°C/W
Typical Thermal Resistance, Junction to Ambient (Notes 5, 6, 7)	R _{θJA}	4.49	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

Notes: 5. Thermal resistance test performed in accordance with JESD-51.
 6. The unit mounted on copper heatsink 71.5mm x 12mm x 0.26mm.
 7. Device mounted on 1inch² copper pad, 2oz. The heat generated must be less than the thermal conductivity from junction to case: dP_D/dT_J < 1/R_{θJC} or junction to ambient: dP_D/dT_J < 1/R_{θJA}.

Electrical Characteristics (@T_C = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Voltage	V _{BR}	650	—	—	V	I _R = 0.1mA
Forward Voltage Drop	V _F	—	1.33 1.67	1.50 2.25	V	I _F = 4A, T _J = +25°C I _F = 4A, T _J = +175°C
Leakage Current	I _R	—	0.11 2.04	20 90	μA	V _R = 650V, T _J = +25°C V _R = 650V, T _J = +175°C
Total Capacitive Charge	Q _C	—	6	—	nC	I _F = 4A, di/dt = 200A/μs, V _R = 400V, T _J = +25°C
Total Capacitance	C _T	—	193 149 38	—	pF	V _R = 0.1V, T _J = +25°C, f = 1MHz V _R = 1V, T _J = +25°C, f = 1MHz V _R = 40V, T _J = +25°C, f = 1MHz

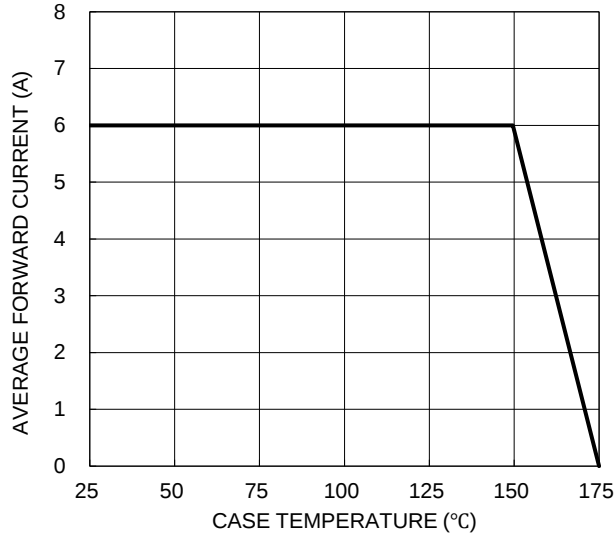


Figure 1. Forward Current Derating Curve

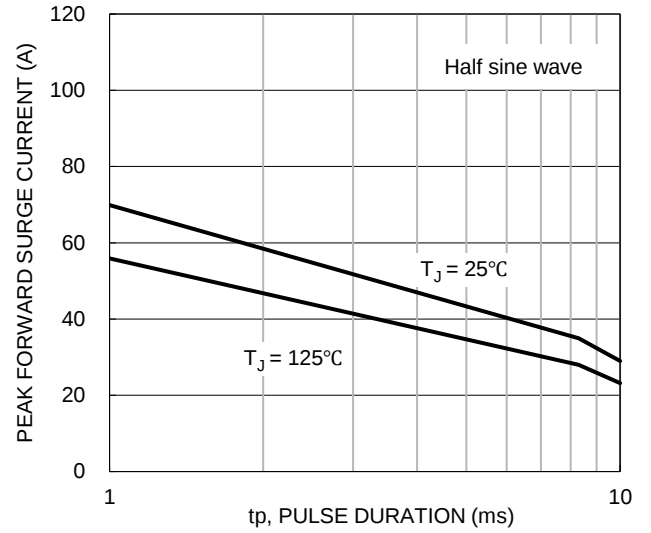


Figure 2. Non-Repetitive Peak Surge Forward Current

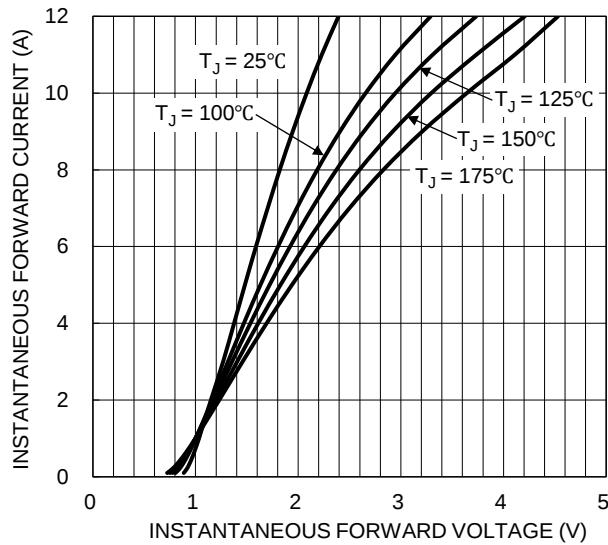


Figure 3. Typical Forward Characteristics

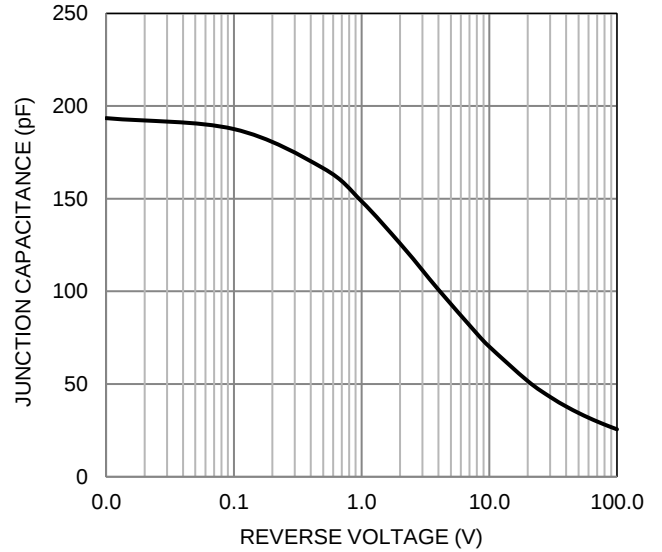


Figure 4. Typical Junction Capacitance

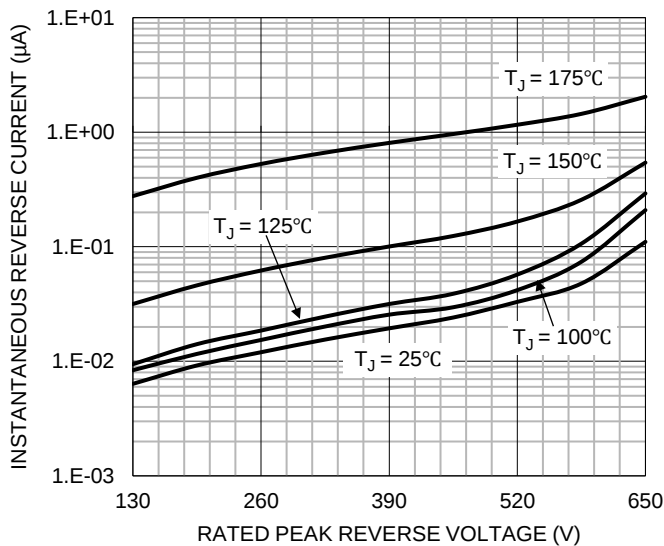


Figure 5. Typical Reverse Characteristics

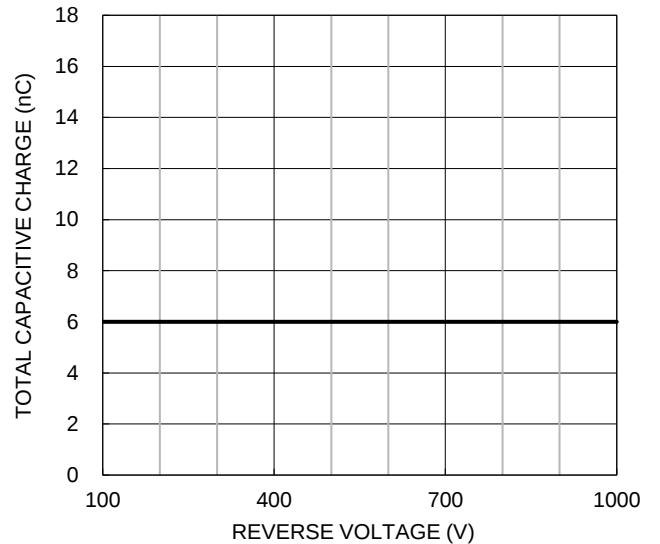
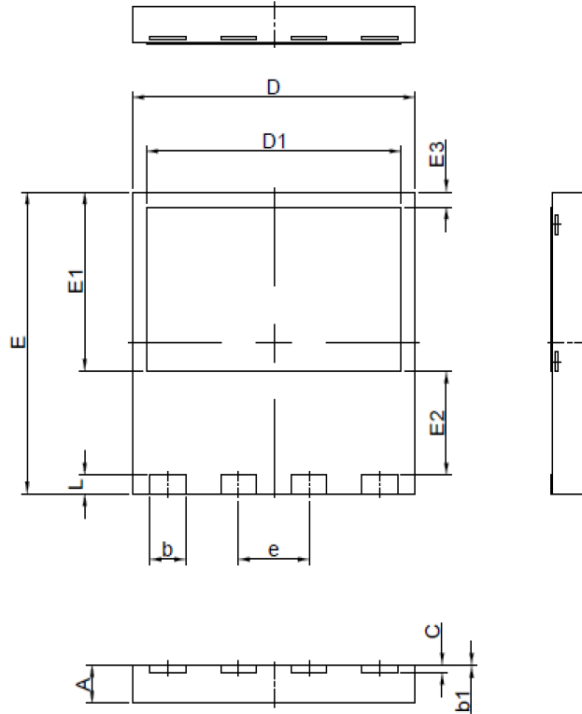


Figure 6. Typical Capacitive Charges

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

DFN8080

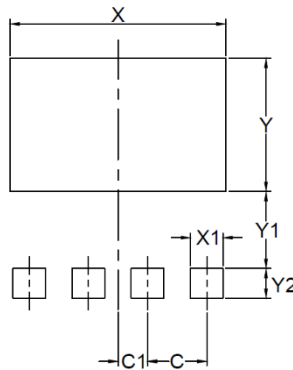


DFN8080			
DIM.	MIN.	MAX.	TYP.
A	0.90	1.10	1.00
b	0.90	1.10	1.00
b1	0	0.05	0.02
C	0.20 REF.		
D	7.90	8.10	8.00
D1	7.10	7.30	7.20
E	7.90	8.10	8.00
E1	4.65	4.85	4.75
E2	2.65	2.85	2.75
E3	0.30	0.50	0.40
e	2.0 BSC		
L	0.40	0.60	0.50
All Dimension in millimeter			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

DFN8080



Dim.	Millimeters
	DFN8080
C	2.0
C1	1.0
X	7.3
X1	1.1
Y	4.5
Y1	2.6
Y2	1.0

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